



NuMicro M051™ Series M058/M0516 Product Brief

The information described in this document is the exclusive intellectual property of Nuvoton Technology Corporation and shall not be reproduced without permission from Nuvoton.

Nuvoton is providing this document only for reference purposes of NuMicro microcontroller based system design. Nuvoton assumes no responsibility for errors or omissions.

All data and specifications are subject to change without notice.

For additional information or questions, please contact: Nuvoton Technology Corporation.



Contents

1	DESCRIPTION.....	3
2	FEATURES.....	4
3	BLOCK DIAGRAM.....	7
4	SELECTION TABLE.....	8
5	PIN CONFIGURATION.....	9
	5.1 QFN 33 pin.....	9
	5.2 LQFP 48 pin.....	10
	5.3 Pin Description.....	11
6	DC ELECTRICAL CHARACTERISTICS.....	14
7	AC ELECTRICAL CHARACTERISTICS.....	19
	7.1 External Crystall.....	19
	7.2 External Oscillator.....	19
	7.3 Typical Crystal Application Circuits.....	20
	7.4 Internal 22.1184MHz RC Oscillator.....	21
	7.5 Internal 10kHz RC Oscillator.....	21
	7.6 Specification of 600k sps 12-bit SARADC.....	22
	7.7 Specification of LDO & Power management.....	23
	7.8 Specification of Low Voltage Reset.....	24
	7.9 Specification of Brownout Detector.....	24
	7.10 Specification of Power-On Reset (5V).....	24
8	APPLICATION CIRCUIT.....	25
9	PACKAGE OUTLINE.....	26
	9.1 48-Pin LQFP.....	26
	9.2 33-Pin QFN.....	27
10	REVISION HISTORY.....	28



1 DESCRIPTION

The NuMicro M051™ series is 32-bit microcontrollers with embedded ARM® Cortex™-M0 core for industrial control and applications which need rich communication interfaces. The Cortex™-M0 is the newest ARM embedded processor with 32-bit performance and at a cost equivalent to traditional 8-bit microcontroller. The NuMicro M051™ series provide various options of products. M058/M0516 is one of excellent products in NuMicro M051™ series.

M058/M0516 can run up to 50MHz. Thus it can afford to support a variety of industrial control and applications which need high CPU performance. M058/M0516 has 32K/64K-byte embedded flash, 4K-byte data flash, 4K-byte flash for the ISP, and 4K-byte embedded SRAM.

Many system level peripheral functions, such as I/O Ports, External Bus Interface(EBI), Timers, UART, SPI, I2C, PWM, ADC, Watchdog Timer and Brownout Detector, have been incorporated into M058/M0516 in order to reduce component count, board space and system cost. These useful functions make M058/M0516 powerful for a wide range of applications.

Additionally, M058/M0516 is equipped with ISP (In-System Programming) and ICP (In-Circuit Programming) functions, which allow the user to update the program memory without removing the chip from the actual end product.



2 FEATURES

- Core
 - ARM® Cortex™ -M0 core runs up to 50 MHz.
 - One 24-bit system timer.
 - Supports low power sleep-mode.
 - Single-cycle 32-bit hardware multiplier.
 - NVIC for the 32 interrupt inputs, each with 4-levels of priority.
 - Serial Wire Debug (SWD) supports with 2 watchpoints/4 breakpoints.
- Memory
 - 32KB/64KB Flash memory for program memory (APROM)
 - 4KB Flash memory for data memory (DataFlash)
 - 4KB Flash memory for loader (LDROM)
 - 4KB SRAM for internal scratch-pad RAM (SRAM)
- Clock Control
 - Programmable system clock source
 - 22.1184MHz internal oscillator (trimmed to 1% accuracy)
 - 10kHz low-power oscillator for Watchdog Timer and wake-up in sleep mode
 - PLL allows CPU operation up to the maximum CPU rate
- I/O Port
 - Up to 40 general-purpose I/O (GPIO) pins
 - Software-configured I/O type
 - ◆ Quasi-bidirectional input/output
 - ◆ Push-pull output
 - ◆ Open-drain output
 - ◆ Input-only
 - Optional Schmitt trigger input
- Timer
 - Four sets of 32-bit Timers
- Watchdog Timer
 - Programmable clock source and timeout period
 - Support wake-up function in power-down mode and power-sleep mode
 - Interrupt or reset selectable when timeout happens
- PWM
 - Built-in up to four 16-bit PWM generators provide eight PWM outputs or four complementary paired PWM outputs



- Individual clock source, clock divider, 8-bit pre-scalar and dead-zone generator for each PWM generator
- PWM interrupt synchronized to PWM period
- 16-bit digital Capture timers (shared with PWM timers) with rising/falling capture inputs
- Support Capture interrupt
- UART
 - Up to two sets UART device.
 - Buffered receiver and transmitter, each with 15 bytes FIFO
 - Optional flow control function (CTS and RTS)
 - Support IrDA(SIR) function
 - Programmable baud-rate generator up to 1/16 system clock
 - Support RS485 function
- SPI
 - Up to two sets SPI device.
 - Master up to 16MHz, and Slave up to 10MHz
 - Support SPI master/slave mode
 - Full duplex synchronous serial data transfer
 - Variable length of transfer data from 1 to 32 bits
 - MSB or LSB first data transfer
 - Rx and Tx on both rising or falling edge of serial clock independently
 - Byte suspend mode in 32-bit transmission
- I2C
 - Master/Slave up to 1Mbit/s (Fast-mode Plus)
 - Bidirectional data transfer between masters and slaves
 - Multi-master bus (no central master).
 - Arbitration between simultaneously transmitting masters without corruption of serial data on the bus
 - Serial clock synchronization allows devices with different bit rates to communicate via one serial bus.
 - Serial clock synchronization can be used as a handshake mechanism to suspend and resume serial transfer.
 - Programmable clocks allow versatile rate control.
 - Support multiple address recognition (two slave address with mask option)

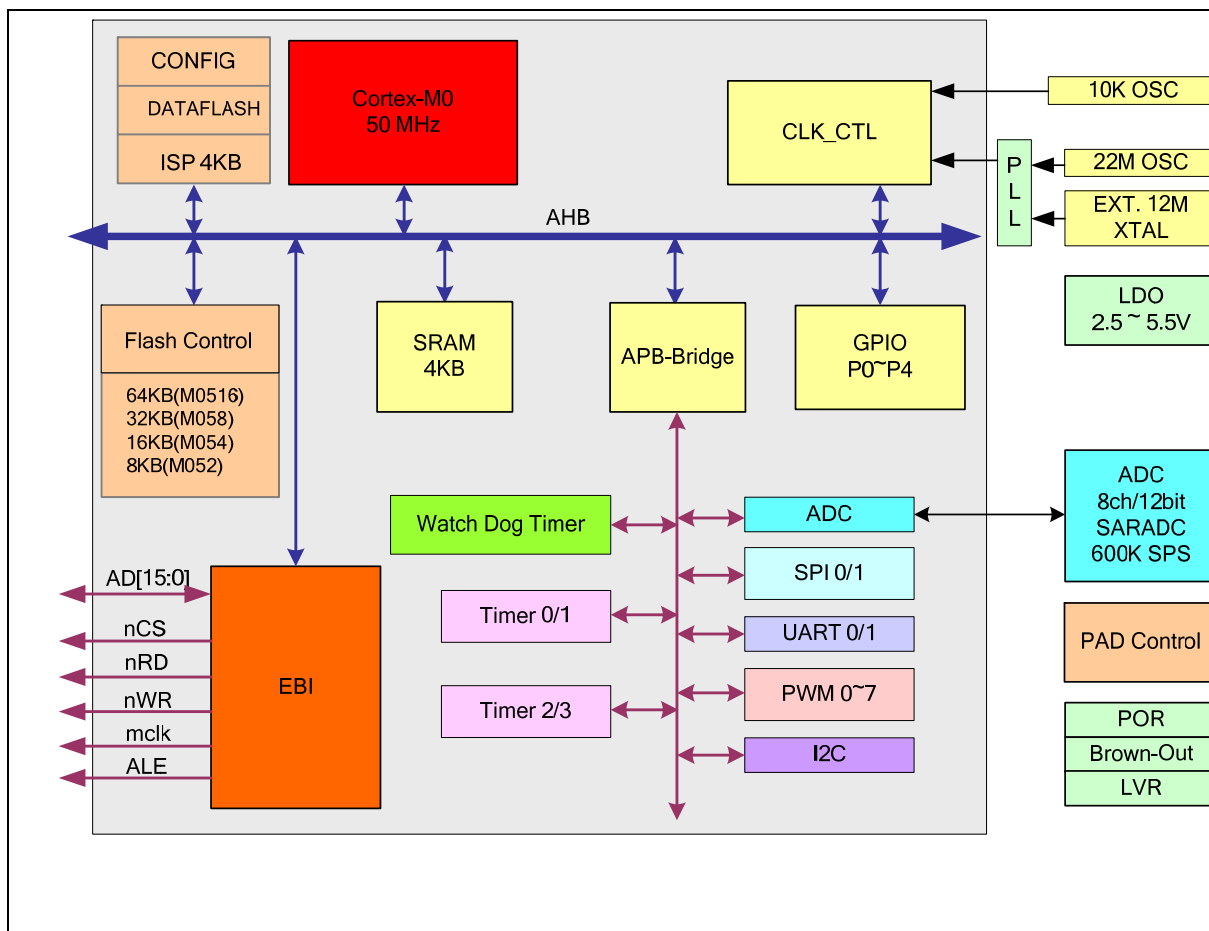


- ADC
 - 12-bit SAR ADC with 600k SPS
 - Up to 8-ch single-end input or 4-ch differential input
 - Single mode/burst mode/single cycle scan mode/continuous scan mode
 - Each channel with individual result register
 - Scan on enabled channels
 - Threshold voltage detection
 - Conversion started by S/W or external pin
- EBI (External Bus Interface) for external memory-mapped device access
- In-System Programming (ISP) & In-Circuit Programming (ICP)
- Brownout Detector
 - Programmable threshold levels: 4.5V/3.8V/2.7V/2.2V
 - Optional brownout interrupt or reset
- Built-in LDO for Wide Operating Voltage Range: 2.5V to 5.5V
- LVR (Low Voltage Reset)
- Operating Temperature: -40°C~85°C
- Packages:
 - Green package (RoHS)
 - 48-pin LQFP, 33-pin QFN



3 BLOCK DIAGRAM

M058/M0516 Block Diagram

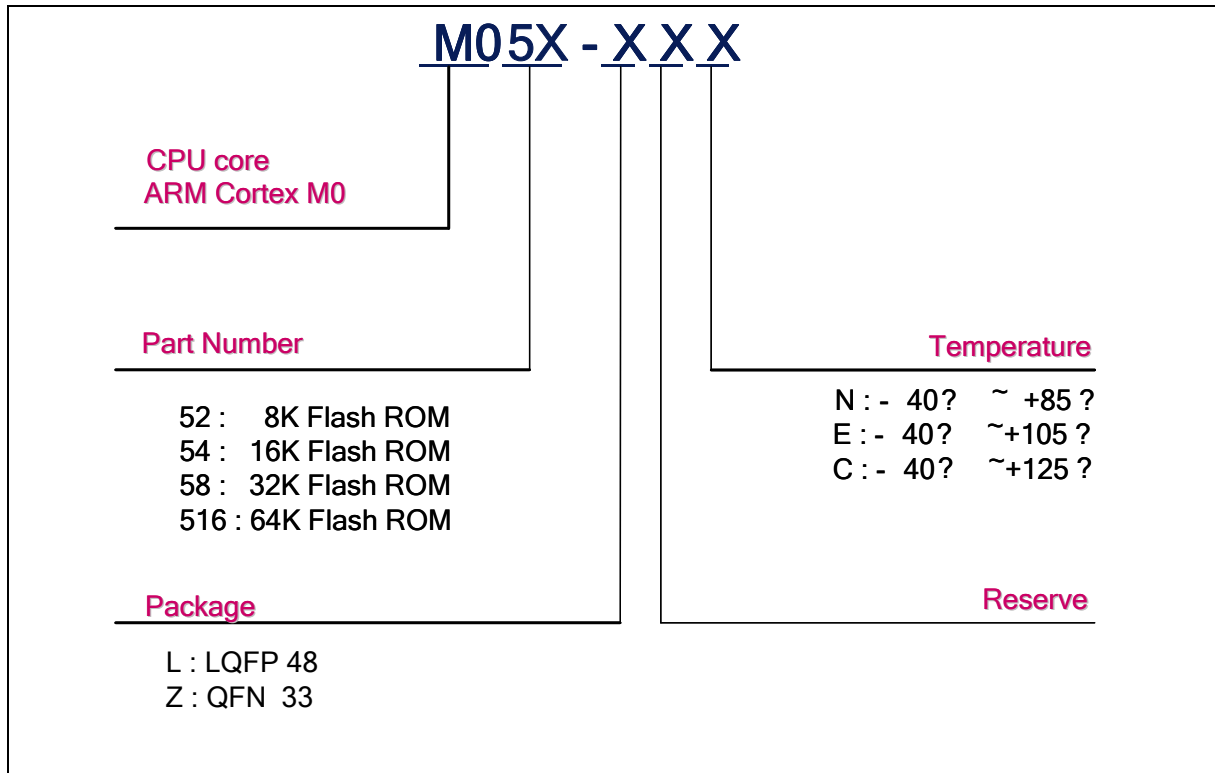




4 SELECTION TABLE

NuMicro M051™ Series Selection Guide

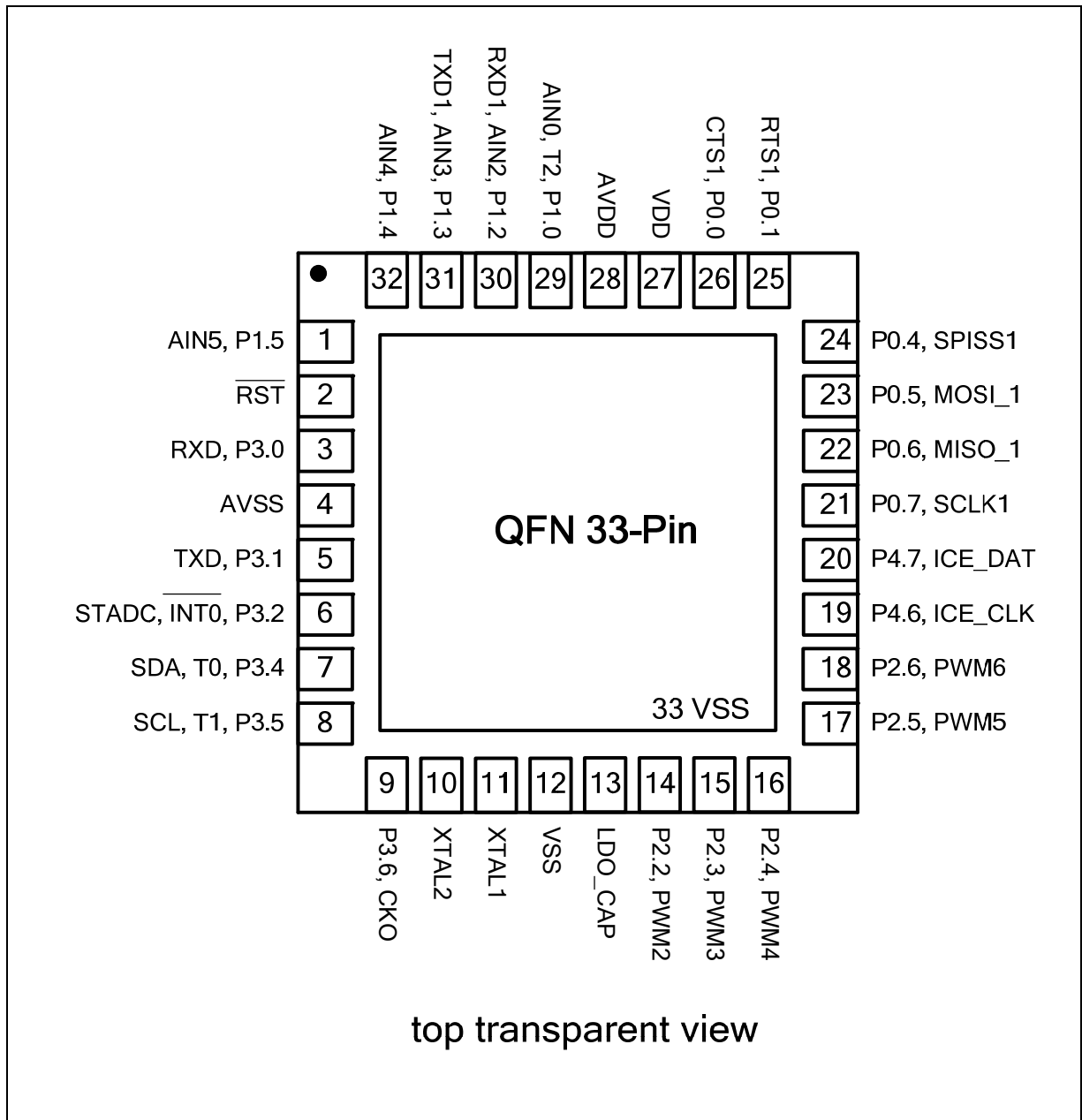
Part No.	APROM	RAM	Data Flash	LDROM	I/O	Timer	Connectivity			PWM	ADC	EBI	ISP ICP	Package
							UART	SPI	I2C					
M058LAN	32K	4K	4K	4K	40	4x32-bit	2	2	1	8	8x12-bit	v	v	LQFP48
M058ZAN	32K	4K	4K	4K	24	4x32-bit	2	1	1	5	5x12-bit		v	QFN33
M0516LAN	64K	4K	4K	4K	40	4x32-bit	2	2	1	8	8x12-bit	v	v	LQFP48
M0516ZAN	64K	4K	4K	4K	24	4x32-bit	2	1	1	5	5x12-bit		v	QFN33





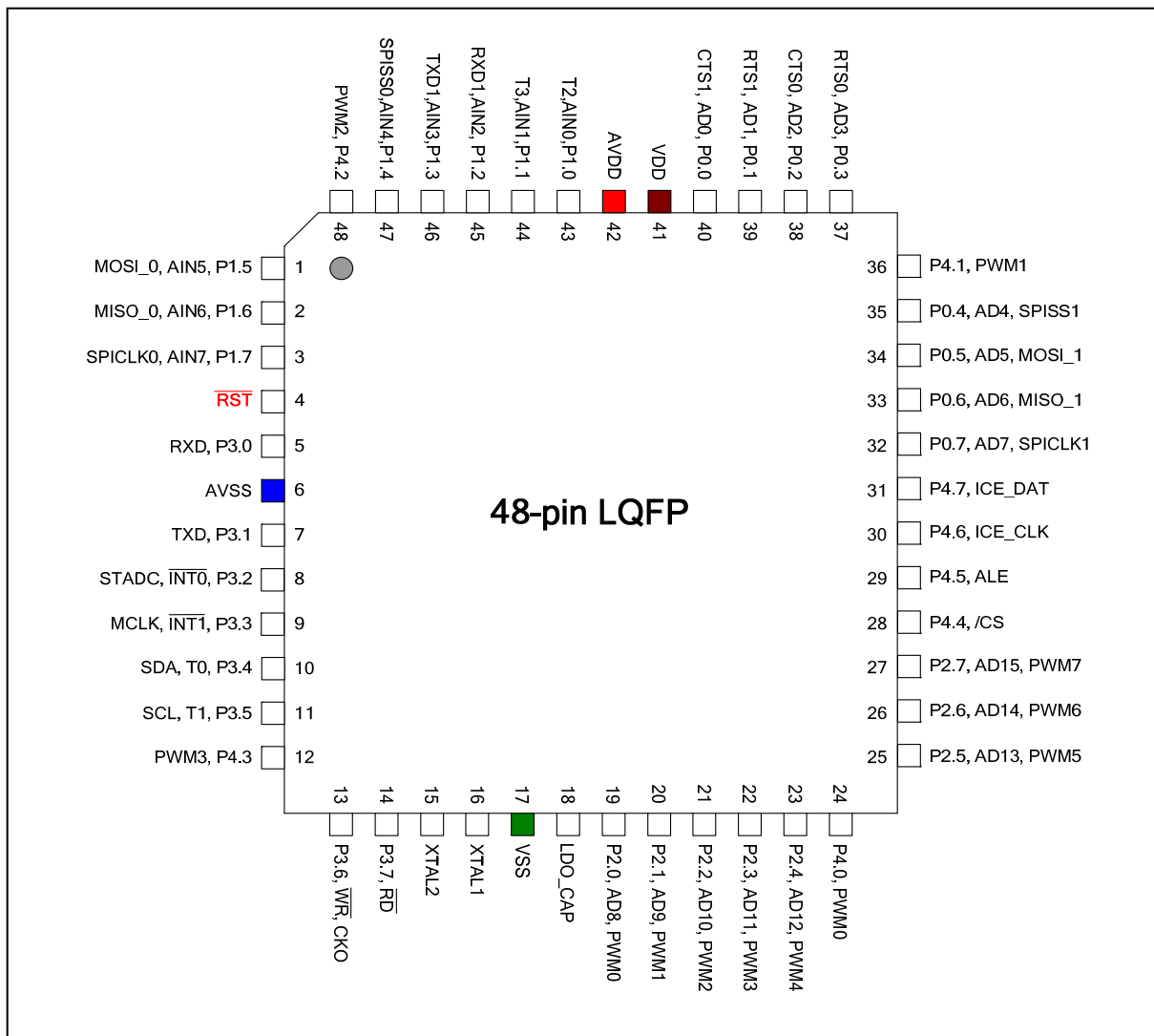
5 PIN CONFIGURATION

5.1 QFN 33 pin





5.2 LQFP 48 pin





5.3 Pin Description

Pin number		Symbol	Alternate Function		Type ^[1]	Description
QFN33	LQFP48		1	2		
11	16	XTAL1			I (ST)	CRYSTAL1: This is the input pin to the internal inverting amplifier. The system clock is from external crystal or resonator when FOSC[1:0] (CONFIG3[1:0]) are both logic 1 by default.
10	15	XTAL2			O	CRYSTAL2: This is the output pin from the internal inverting amplifier. It emits the inverted signal of XTAL1.
27	41	VDD			P	POWER SUPPLY: Supply voltage Digital V _{DD} for operation.
12	17	VSS			P	GROUND: Digital Ground potential.
33						
28	42	AVDD			P	POWER SUPPLY: Supply voltage Analog AV _{DD} for operation.
4	6	AVSS			P	GROUND: Analog Ground potential.
13	18	LDO_C AP			P	LDO: LDO output pin Note: It needs to be connected with a 10uF capacitor.
2	4	/RST			I (ST)	RESET: /RST pin is a Schmitt trigger input pin for hardware device reset. A "Low" on this pin for 768 clock counter of Internal RC 22M while the system clock is running will reset the device. /RST pin has an internal pull-up resistor allowing power-on reset by simply connecting an external capacitor to GND.
26	40	P0.0	CTS1	AD0	D, I/O	PORT0: Port 0 is an 8-bit four mode output pin and two mode input. Its multifunction pins are for CTS1, RTS1, CTS0, RTS0, SPISS1, MOSI_1, MISO_1, and SPICLK1. P0 has an alternative function as AD[7:0] while external memory accessing. During the external memory access, P0 will output high will be internal strong pulled-up rather than weak pull-up in order to drive out high byte address for external devices. These pins which are SPISS1, MOSI_1, MISO_1, and SPICLK1 for the SPI function used. CTS0/1: Clear to Send input pin for UART0/1 RTS0/1: Request to Send output pin for UART0/1
25	39	P0.1	RTS1	AD1	D, I/O	
NC	38	P0.2	CTS0	AD2	D, I/O	
NC	37	P0.3	RTS0	AD3	D, I/O	
24	35	P0.4	SPISS1	AD4	D, I/O	
23	34	P0.5	MOSI_1	AD5	D, I/O	
22	33	P0.6	MISO_1	AD6	D, I/O	
21	32	P0.7	SPICLK1	AD7	D, I/O	



Pin number		Symbol	Alternate Function		Type ^[1]	Description
QFN33	LQFP48		1	2		
29	43	P1.0	T2	AIN0	I/O	PORT1: Port 1 is an 8-bit four mode output pin and two mode input. Its multifunction pins are for T2, T3, RXD1, TXD1, SPISS0, MOSI_0, MISO_0, and SPICLK0. These pins which are SPISS0, MOSI_0, MISO_0, and SPICLK0 for the SPI function used. These pins which are AIN0~AIN7 for the 12 bits ADC function used. The RXD1/TXD1 pins are for UART1 function used.
NC	44	P1.1	T3	AIN1	I/O	
30	45	P1.2	RXD1	AIN2	I/O	
31	46	P1.3	TXD1	AIN3	I/O	
32	47	P1.4	SPISS0	AIN4	I/O	
1	1	P1.5	MOSI_0	AIN5	I/O	
NC	2	P1.6	MISO_0	AIN6	I/O	
NC	3	P1.7	SPICLK0	AIN7	I/O	
NC	19	P2.0	PWM0	AD8	D, I/O	PORT2: Port 2 is an 8-bit four mode output pin and two mode input. It has an alternative function P2 has an alternative function as AD[15:8] while external memory accessing. During the external memory access, P2 will output high will be internal strong pulled-up rather than weak pull-up in order to drive out high byte address for external devices. These pins which are PWM0~PWM7 for the PWM function used in the LQFP48 package.
NC	20	P2.1	PWM1	AD9	D, I/O	
14	21	P2.2	PWM2	AD10	D, I/O	
15	22	P2.3	PWM3	AD11	D, I/O	
16	23	P2.4	PWM4	AD12	D, I/O	
17	25	P2.5	PWM5	AD13	D, I/O	
18	26	P2.6	PWM6	AD14	D, I/O	
NC	27	P2.7	PWM7	AD15	D, I/O	
3	5	P3.0	RXD		I/O	PORT3: Port 3 is an 8-bit four mode output pin and two mode input. Its multifunction pins are for RXD, TXD, $\overline{\text{INT0}}$, $\overline{\text{INT1}}$, T0, T1, $\overline{\text{WR}}$, and $\overline{\text{RD}}$. The RXD/TXD pins are for UART0 function used. The SDA/SCK pins are for I2C function used. MCLK: EBI clock output pin. CKO: HCLK clock output The STADC pin is for ADC external trigger input.
5	7	P3.1	TXD		I/O	
6	8	P3.2	$\overline{\text{INT0}}$	STADC	I/O	
NC	9	P3.3	$\overline{\text{INT1}}$	MCLK	I/O	
7	10	P3.4	T0	SDA	I/O	
8	11	P3.5	T1	SCL	I/O	



Pin number		Symbol	Alternate Function		Type ^[1]	Description
QFN33	LQFP48		1	2		
9	13	P3.6	\overline{WR}	CKO	I/O	PORT4: Port 4 is an 8-bit four mode output pin and two mode input. Its multifunction pins are for /CS, ALE, ICE_CLK and ICE_DAT. /CS for EBI (External Bus Interface) used. ALE (Address Latch Enable) is used to enable the address latch that separates the address from the data on Port 0 and Port 2. The ICE_CLK/ICE_DAT pins are for JTAG-ICE function used. PWM0-3 can be used from P4.0-P4.3 when EBI is active.
NC	14	P3.7	\overline{RD}		I/O	
NC	24	P4.0	PWM0		I/O	
NC	36	P4.1	PWM1		I/O	
NC	48	P4.2	PWM2		I/O	
NC	12	P4.3	PWM3		I/O	
NC	28	P4.4	/CS		I/O	
NC	29	P4.5	ALE		I/O	
19	30	P4.6	ICE_CLK		I/O	
20	31	P4.7	ICE_DAT		I/O	

[1] I/O type description. I: input, O: output, I/O: quasi bi-direction, D: open-drain, P: power pin, ST: Schmitt trigger.



6 DC ELECTRICAL CHARACTERISTICS

(V_{DD}-V_{SS}=2.5~5.5V, T_A = 25°C, F_{OSC} = 50MHz unless otherwise specified.)

PARAMETER	SYM	SPECIFICATION				TEST CONDITIONS
		MIN	TYP	MAX	UNIT	
Operation voltage	V _{DD}	2.5		5.5	V	V _{DD} =2.5V~5.5V up to 50 MHz
Power Ground	V _{SS} AV _{SS}	-0.3			V	
LDO Output Voltage	V _{LDO}	-10%	2.45	+10%	V	V _{DD} > 2.7V
Band Gap Analog Input	V _{BG}	-5%	1.26	+5%	V	V _{DD} =2.5V ~ 5.5V
Analog Operating Voltage	AV _{DD}	3.0		V _{DD}	V	
Operating Current Normal Run Mode @ 50Mhz	I _{DD1}		32		mA	V _{DD} = 5.5V enable all IP and PLL , XTAL=12MHz
	I _{DD2}		24		mA	V _{DD} =5.5V disable all IP and enable PLL , XTAL=12MHz
	I _{DD3}		31		mA	V _{DD} = 3V enable all IP and PLL , XTAL=12MHz
	I _{DD4}		23		mA	V _{DD} = 3V disable all IP and enable PLL , XTAL=12MHz
Operating Current Normal Run Mode @ 12Mhz	I _{DD5}		17		mA	V _{DD} = 5.5V enable all IP and disable PLL , XTAL=12MHz
	I _{DD6}		14		mA	V _{DD} = 5.5V disable all IP and disable PLL , XTAL=12MHz
	I _{DD7}		16		mA	V _{DD} = 3V enable all IP and disable PLL , XTAL=12MHz
	I _{DD8}		13		mA	V _{DD} = 3V disable all IP and disable PLL , XTAL=12MHz



PARAMETER	SYM	SPECIFICATION				TEST CONDITIONS
		MIN	TYP	MAX	UNIT	
Operating Current Normal Run Mode @ 4Mhz	I _{DD9}		12		mA	V _{DD} = 5.5V enable all IP and disable PLL , XTAL=4MHz
	I _{DD10}		10		mA	V _{DD} = 5.5V disable all IP and disable PLL , XTAL=4MHz
	I _{DD11}		10		mA	V _{DD} = 3V enable all IP and disable PLL , XTAL=4MHz
	I _{DD12}		9		mA	V _{DD} = 3V disable all IP and disable PLL , XTAL=4MHz
Operating Current Idle Mode @ 50Mhz	I _{IDLE1}		19		mA	V _{DD} = 5.5V enable all IP and PLL , XTAL=12MHz
	I _{IDLE2}		11		mA	V _{DD} =5.5V disable all IP and enable PLL , XTAL=12MHz
	I _{IDLE3}		18		mA	V _{DD} = 3V enable all IP and PLL , XTAL=12MHz
	I _{IDLE4}		10		mA	V _{DD} = 3V disable all IP and enable PLL , XTAL=12MHz
Operating Current Idle Mode @ 12Mhz	I _{IDLE5}		10		mA	V _{DD} = 5.5V enable all IP and disable PLL , XTAL=12MHz
	I _{IDLE6}		7		mA	V _{DD} = 5.5V disable all IP and disable PLL , XTAL=12MHz
	I _{IDLE7}		9		mA	V _{DD} = 3V enable all IP and disable PLL , XTAL=12MHz
	I _{IDLE8}		6		mA	V _{DD} = 3V disable all IP and disable PLL , XTAL=12MHz
Operating Current Idle Mode @ 4Mhz	I _{IDLE9}		5		mA	V _{DD} = 5.5V enable all IP and disable PLL , XTAL=4MHz
	I _{IDLE10}		4		mA	V _{DD} = 5.5V disable all IP and disable PLL , XTAL=4MHz
	I _{IDLE11}		4		mA	V _{DD} = 3V enable all IP and disable PLL , XTAL=4MHz
	I _{IDLE12}		3		mA	V _{DD} = 3V disable all IP and disable PLL , XTAL=4MHz
Standby Current	I _{PWD1}		15		μA	V _{DD} = 5.5V, No load @ Disable BOV function



PARAMETER	SYM	SPECIFICATION				TEST CONDITIONS
		MIN	TYP	MAX	UNIT	
Power-down Mode (Deep Sleep Mode)	$I_{P_{WD2}}$		11		μA	$V_{DD} = 3.0V$, No load @ Disable BOV function



PARAMETER	SYM	SPECIFICATION				TEST CONDITIONS
		MIN	TYP	MAX	UNIT	
Input Current P0/1/2/3/4	I_{IN1}	-60	-	+15	μA	$V_{DD} = 5.5\text{V}$, $V_{IN} = 0\text{V}$ or $V_{IN} = V_{DD}$
Input Leakage Current P0/1/2/3/4	I_{LK}	-2	-	+2	μA	$V_{DD} = 5.5\text{V}$, $0 < V_{IN} < V_{DD}$
Logic 1 to 0 Transition Current P0/1/2/3/4 (Quasi-bidirectional mode)	$I_{TL}^{[3]}$		-600	-200	μA	$V_{DD} = 5.5\text{V}$, $V_{IN} < 2.0\text{V}$
Input Low Voltage P0/1/2/3/4 (TTL input)	V_{IL1}	-0.3	-	0.8	V	$V_{DD} = 4.5\text{V}$
		-0.3	-	0.6		$V_{DD} = 2.5\text{V}$
Input High Voltage P0/1/2/3/4 (TTL input)	V_{IH1}	2.0	-	$V_{DD} + 0.2$	V	$V_{DD} = 5.5\text{V}$
		1.5	-	$V_{DD} + 0.2$		$V_{DD} = 3.0\text{V}$
Input Low Voltage XT1 ^[2]	V_{IL3}	0	-	0.8	V	$V_{DD} = 4.5\text{V}$
		0	-	0.4		$V_{DD} = 3.0\text{V}$
Input High Voltage XT1 ^[2]	V_{IH3}	3.5	-	$V_{DD} + 0.2$	V	$V_{DD} = 5.5\text{V}$
		2.4	-	$V_{DD} + 0.2$		$V_{DD} = 3.0\text{V}$
Negative going threshold (Schmitt input), /RST	V_{ILS}	-0.5	-	$0.3V_D$	V	
Positive going threshold (Schmitt input), /RST	V_{IHS}	$0.7V_D$	-	$V_{DD} + 0.5$	V	
Internal /RST pin pull up resistor	R_{RST}	40		150	K Ω	
Negative going threshold (Schmitt input), P0/1/2/3/4	V_{ILS}	-0.5	-	$0.2V_D$	V	
Positive going threshold (Schmitt input), P0/1/2/3/4	V_{IHS}	$0.4V_D$	-	$V_{DD} + 0.5$	V	
Source Current P0/1/2/3/4 (Quasi-bidirectional Mode)	I_{SR11}	-300	-370	-450	μA	$V_{DD} = 4.5\text{V}$, $V_S = 2.4\text{V}$
	I_{SR12}	-50	-70	-90	μA	$V_{DD} = 2.7\text{V}$, $V_S = 2.2\text{V}$
	I_{SR12}	-40	-60	-80	μA	$V_{DD} = 2.5\text{V}$, $V_S = 2.0\text{V}$
Source Current P0/1/2/3/4 (Push-pull Mode)	I_{SR21}	-20	-24	-28	mA	$V_{DD} = 4.5\text{V}$, $V_S = 2.4\text{V}$
	I_{SR22}	-4	-6	-8	mA	$V_{DD} = 2.7\text{V}$, $V_S = 2.2\text{V}$
	I_{SR22}	-3	-5	-7	mA	$V_{DD} = 2.5\text{V}$, $V_S = 2.0\text{V}$
Sink Current P0/1/2/3/4 (Quasi-bidirectional and Push-pull Mode)	I_{SK1}	10	16	20	mA	$V_{DD} = 4.5\text{V}$, $V_S = 0.45\text{V}$
	I_{SK1}	7	10	13	mA	$V_{DD} = 2.7\text{V}$, $V_S = 0.45\text{V}$
	I_{SK1}	6	9	12	mA	$V_{DD} = 2.5\text{V}$, $V_S = 0.45\text{V}$



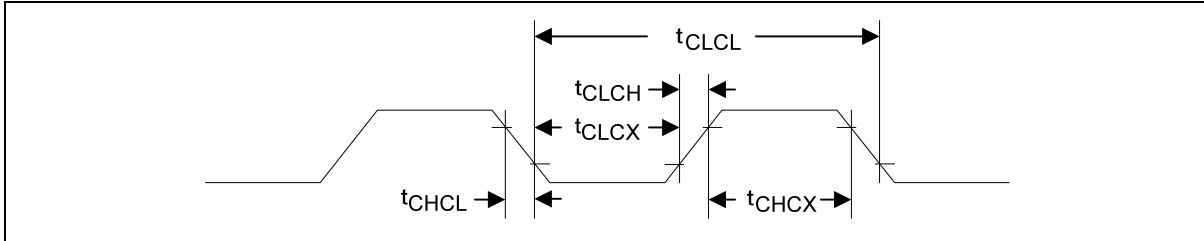
PARAMETER	SYM	SPECIFICATION				TEST CONDITIONS
		MIN	TYP	MAX	UNIT	
Brownout voltage with BOV_VL [1:0] =00b	V _{BO2.2}	2.1	2.2	2.3	V	
Brownout voltage with BOV_VL [1:0] =01b	V _{BO2.7}	2.6	2.7	2.8	V	
Brownout voltage with BOV_VL [1:0] =10b	V _{BO3.8}	3.7	3.8	3.9	V	
Brownout voltage with BOV_VL [1:0] =11b	V _{BO4.5}	4.4	4.5	4.6	V	
Hysteresis range of BOD voltage	V _{BH}	30	-	150	mV	V _{DD} = 2.5V~5.5V

Notes:

1. /RST pin is a Schmitt trigger input.
2. XTAL1 is a CMOS input.
3. Pins of P0, P1, P2, P3 and P4 can source a transition current when they are being externally driven from 1 to 0. In the condition of V_{DD}=5.5V, the transition current reaches its maximum value when Vin approximates to 2V.

7 AC ELECTRICAL CHARACTERISTICS

7.1 External Crystal



Note: Duty cycle is 50%.

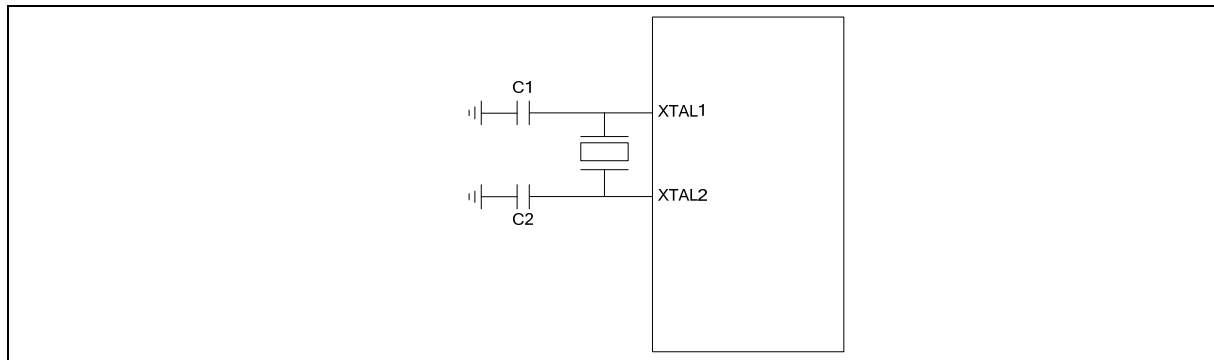
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	CONDITION
Clock High Time	t_{CHCX}	20	-	125	nS	
Clock Low Time	t_{CLCX}	20	-	125	nS	
Clock Rise Time	t_{CLCH}	-	-	10	nS	
Clock Fall Time	t_{CHCL}	-	-	10	nS	

7.2 External Oscillator

PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNIT
Input clock frequency	External crystal	4	12	24	MHz
Temperature	-	-40	-	85	°C
V_{DD}	-	2.5	5	5.5	V
Operating current	12MHz@ $V_{DD} = 5V$	-	5	-	mA

7.3 Typical Crystal Application Circuits

CRYSTAL	C1	C2
4MHz ~ 24 MHz	Optional (Depend on crystal specification)	





7.4 Internal 22.1184MHz RC Oscillator

PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply voltage ^[1]	-	2.5	-	5.5	V
Center Frequency	-	-	22.1184	-	MHz
Calibrated Internal Oscillator Frequency	+25°C; V _{DD} =5V	-1	-	+1	%
	-40°C~+85°C; V _{DD} =2.5V~5.5V	-3	-	+3	%
Accuracy of Un-calibrated Internal Oscillator Frequency	-40°C~+85°C; V _{DD} =2.5V~5.5V	-25	-	+25	%
Operating current	V _{DD} =5V	-	500	-	uA

7.5 Internal 10kHz RC Oscillator

PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply voltage ^[1]	-	2.5	-	5.5	V
Center Frequency	-	-	10	-	kHz
Calibrated Internal Oscillator Frequency	+25°C; V _{DD} =5V	-30	-	+30	%
	-40°C~+85°C; V _{DD} =2.5V~5.5V	-50	-	+50	%
Operating current	V _{DD} =5V	-	5	-	uA

Notes:

1. Internal operation voltage comes from LDO.



7.6 Specification of 600k sps 12-bit SARADC

PARAMETER	SYM.	MIN.	TYP.	MAX.	UNIT
Resolution	-	-	-	12	Bit
Differential nonlinearity error	DNL	-	± 1.2	-	LSB
Integral nonlinearity error	INL	-	± 1.5	-	LSB
Offset error	EO	-	+4		LSB
Gain error (Transfer gain)	EG	-	+7		LSB
Monotonic	-	Guaranteed			-
ADC clock frequency	FADC	-	-	20	MHz
Calibration time	TCAL	-	127	-	Clock
Sample time	TS	-	7	-	Clock
Conversion time	TADC	-	13	-	Clock
Sample rate	FS	-	-	600	k sps
Supply voltage	V _{LDO}	-	2.5	-	V
	V _{ADD}	3	-	5.5	V
Supply current (Avg.)	IDD	-	0.5	-	mA
	IDDA	-	1.5	-	mA
Input voltage range	V _{IN}	0	-	AVDD	V
Capacitance	C _{IN}	-	5	-	pF



7.7 Specification of LDO & Power management

PARAMETER	MIN	TYP	MAX	UNIT	NOTE
Input Voltage	2.7	5	5.5	V	V _{DD} input voltage
Output Voltage (bypass=0)	-10%	2.45	+10%	V	LDO output voltage
Output Voltage (bypass=1)	-10%	Input Voltage	+10%	V	Input Voltage < 2.7V
Temperature	-40	25	85	oC	
Quiescent Current (PD=0, bypass=0)	-	100	-	uA	
Quiescent Current (PD=1, bypass=0)	-	5	-	uA	
Quiescent Current (PD=1, bypass=1)	-	5	-	uA	
Iload (PD=0)	-	-	100	mA	
Iload (PD=1)	-	-	100	uA	
Cbp	-	1u	-	F	Resr=1ohm
Cload	-	250p	-	F	

Note:

1. It is recommended that a 10uF or higher capacitor and a 100nF bypass capacitor are connected between VDD and the closest VSS pin of the device.
2. For ensuring power stability, a 4.7uF or higher capacitor must be connected between LDO pin and the closest VSS pin of the device. Also a 100nF bypass capacitor between LDO and VSS help suppressing output noise.



7.8 Specification of Low Voltage Reset

PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNIT
Operation voltage	-	1.7	-	5.5	V
Quiescent current	VDD5V=5.5V	-	-	5	uA
Temperature	-	-40	25	85	°C
Threshold voltage	Temperature=25°	1.7	2.0	2.3	V
	Temperature=-40°	-	2.4	-	V
	Temperature=85°	-	1.6	-	V
Hysteresis	-	0	0	0	V

7.9 Specification of Brownout Detector

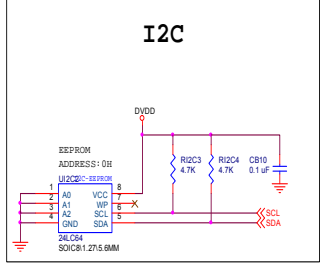
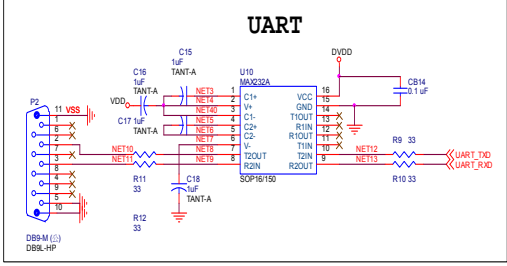
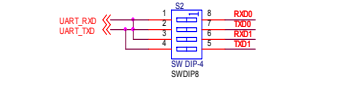
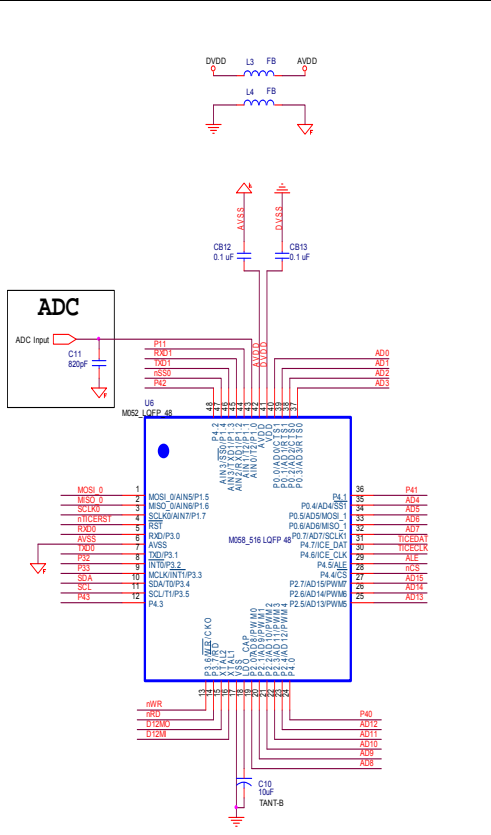
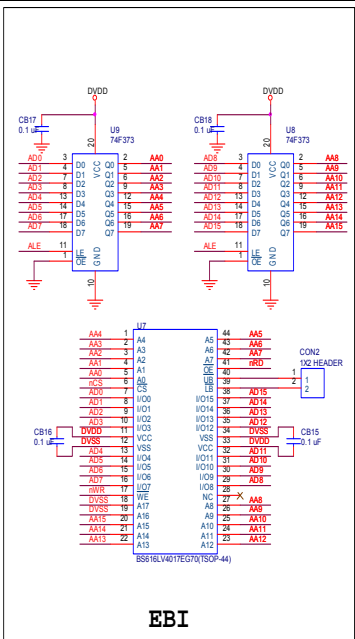
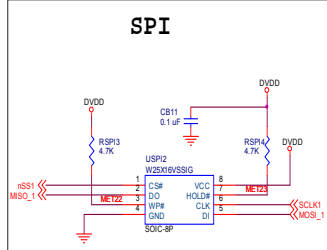
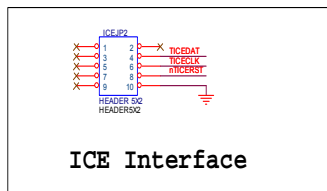
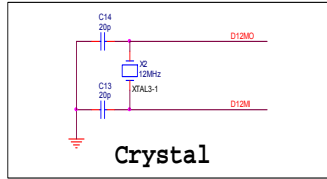
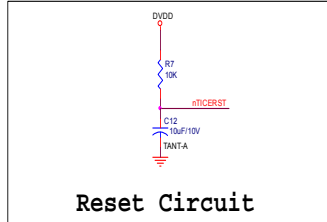
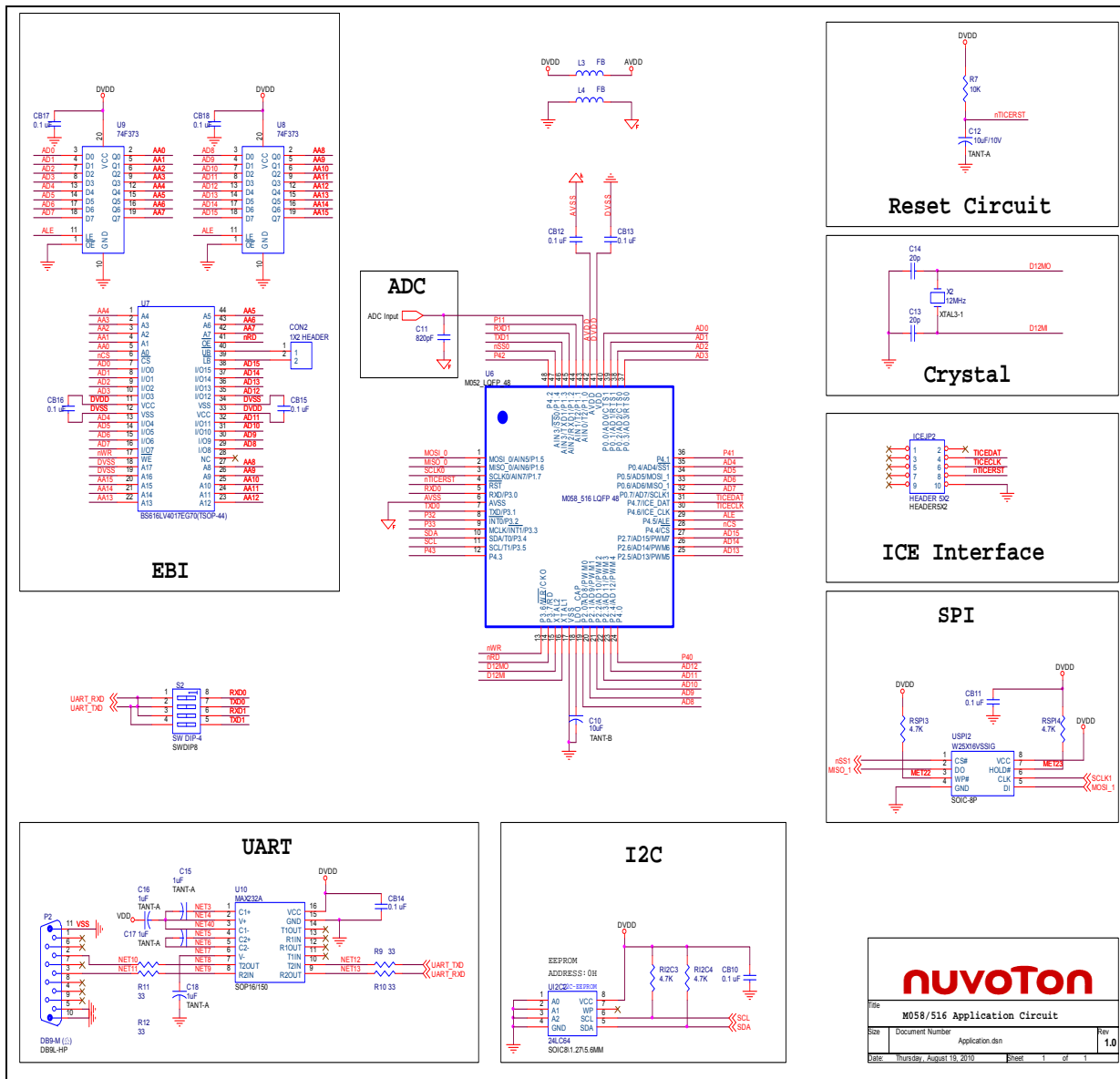
Parameter	Condition	Min.	Typ.	Max.	Unit
Operation voltage	-	2.5	-	5.5	V
Quiescent current	AVDD=5.5V	-	-	125	μA
Temperature	-	-40	25	85	°C
Brown-out voltage	BOV_VL[1:0]=11	4.4	4.5	4.6	V
	BOV_VL [1:0]=10	3.7	3.8	3.9	V
	BOV_VL [1:0]=01	2.6	2.7	2.8	V
	BOV_VL [1:0]=00	2.1	2.2	2.3	V
Hysteresis	-	30m	-	150m	V

7.10 Specification of Power-On Reset (5V)

Parameter	Condition	Min.	Typ.	Max.	Unit
Temperature	-	-40	25	85	°C
Reset voltage	V+	-	2	-	V
Quiescent current	Vin>reset voltage	-	1	-	nA



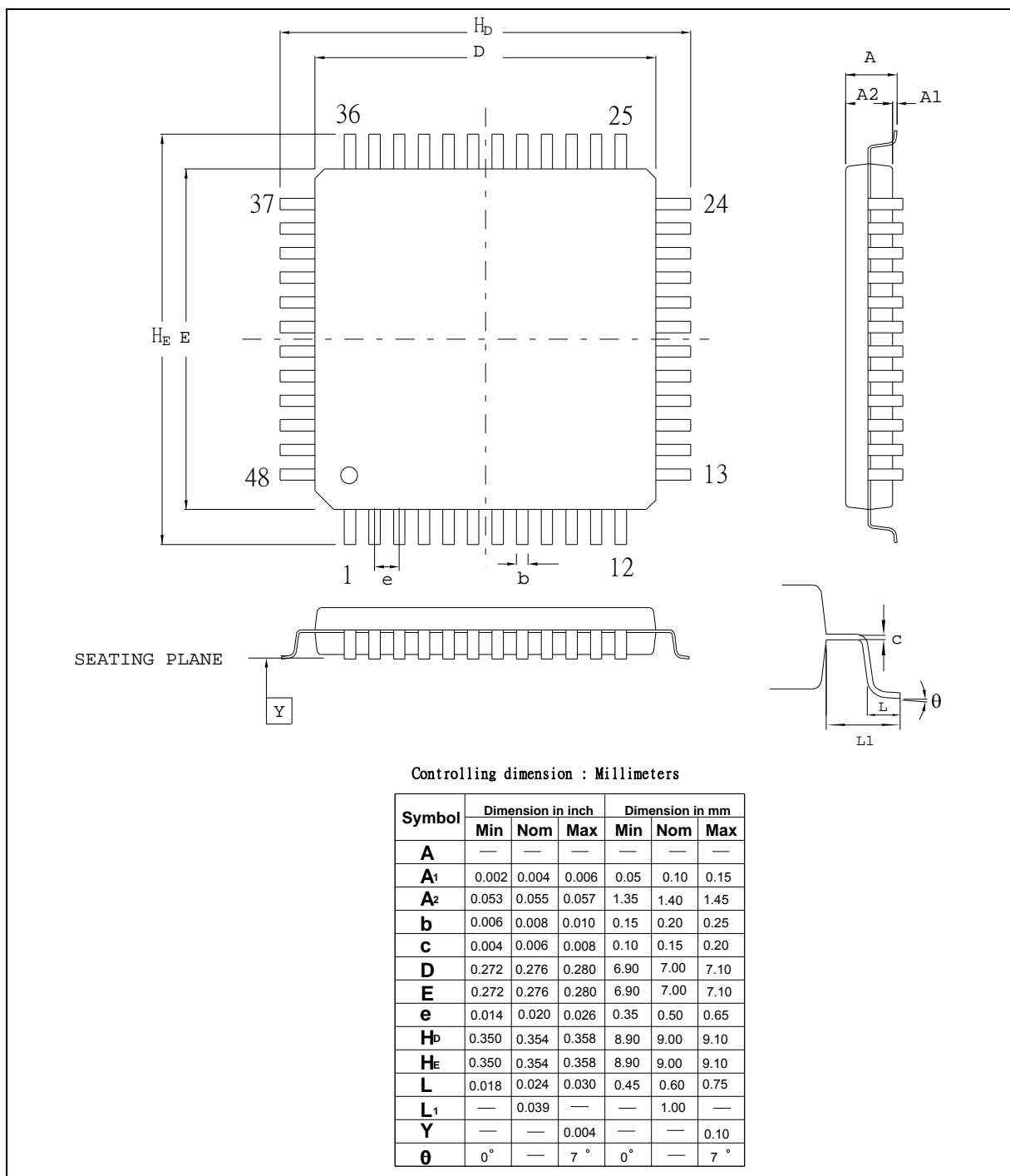
8 APPLICATION CIRCUIT



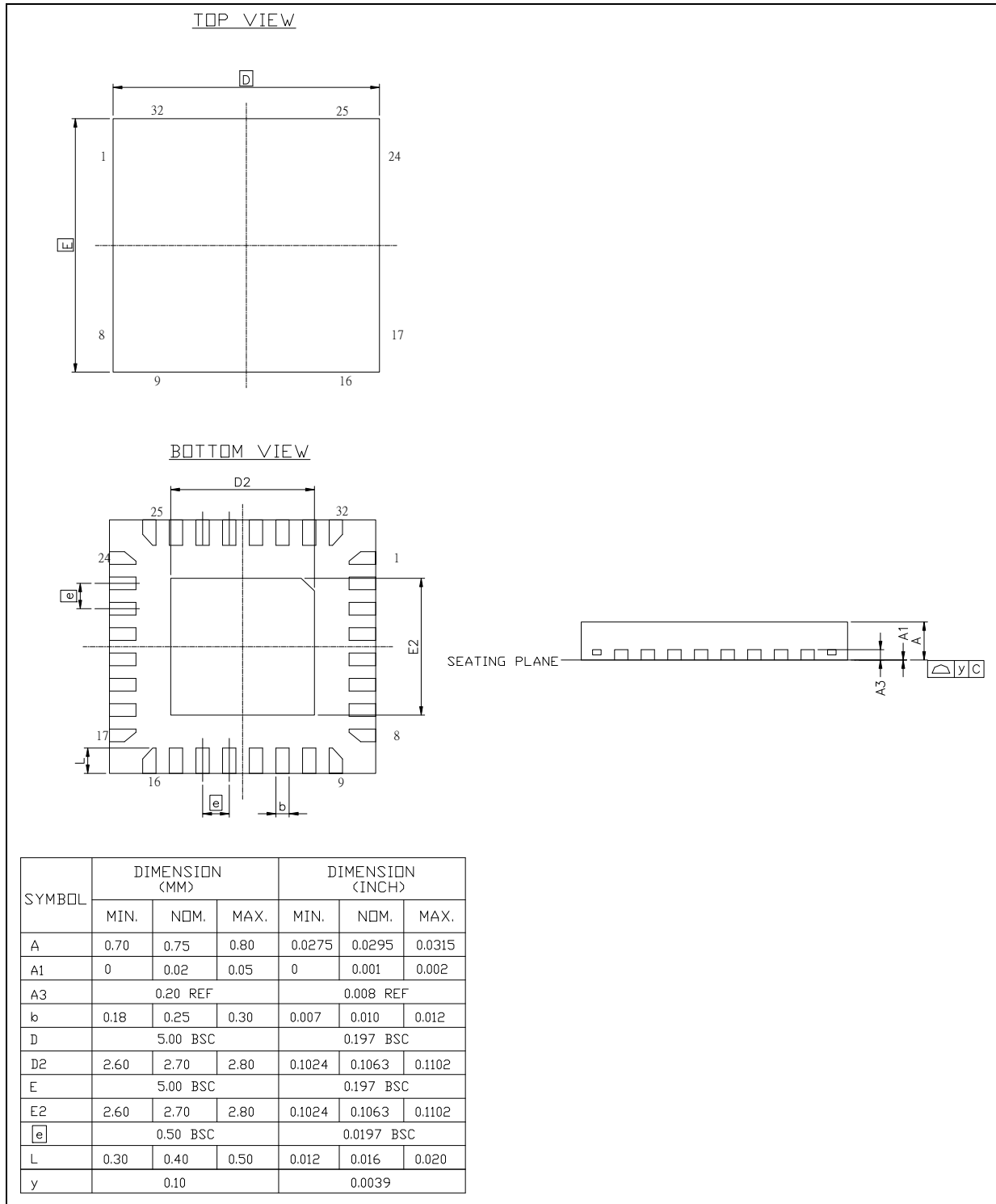
nuvoTon			
Title: M058/516 Application Circuit			
Size:	Document Number:	Application: dsn	Rev: 1.0
Date:	Thursday, August 19, 2010	Sheet:	1 of 1

9 PACKAGE OUTLINE

9.1 48-Pin LQFP



9.2 33-Pin QFN





10 REVISION HISTORY

VERSION	DATE	PAGE/ CHAP.	DESCRIPTION
V1.0	Aug 19, 2010	-	Initial issued

Important Notice

Nuvoton products are not designed, intended, authorized or warranted for use as components in systems or equipment intended for surgical implantation, atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, or for other applications intended to support or sustain life. Further more, Nuvoton products are not intended for applications wherein failure of Nuvoton products could result or lead to a situation wherein personal injury, death or severe property or environmental damage could occur.

Nuvoton customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Nuvoton for any damages resulting from such improper use or sales.

Please note that all data and specifications are subject to change without notice. All the trademarks of products and companies mentioned in this datasheet belong to their respective owners.

*Please note that all data and specifications are subject to change without notice.
All the trademarks of products and companies mentioned in this datasheet belong to their respective owners.*